

preliminary

Schottky	Diode	Gen	2
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V_{RRM}	=	100 V
I _{FAV}	<i>=</i> 2x	15 A
VF	=	0.73 V

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

Part number

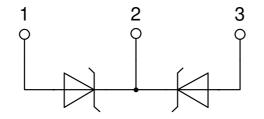
DSA30C100PN



Backside: isolated



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Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
 Low voltage peaks for reduced
- protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220FP

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

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Schottky	1				Rating	5	
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blockir	ng voltage	$T_{VJ} = 25^{\circ}C$			100	V
V _{RRM}	max. repetitive reverse blocking vo	ltage	$T_{VJ} = 25^{\circ}C$			100	V
I _R	reverse current, drain current	$V_{R} = 100 V$	$T_{VJ} = 25^{\circ}C$			250	μA
		V_{R} = 100 V	$T_{vJ} = 125^{\circ}C$			2.5	mA
V _F	forward voltage drop	I _F = 15 A	$T_{VJ} = 25^{\circ}C$			0.91	V
		I _F = 30 A				1.08	V
		I _F = 15 A	T _{vJ} = 125°C			0.73	V
		$I_{F} = 30 \text{ A}$				0.91	V
IFAV	average forward current	$T_c = 120^{\circ}C$	$T_{vJ} = 175^{\circ}C$			15	Α
		rectangular d = 0.5					
V _{F0}	threshold voltage		$T_{VJ} = 175^{\circ}C$			0.46	V
r _F	slope resistance } for power los	ss calculation only				12.4	mΩ
R _{thJC}	thermal resistance junction to case	,				4.2	K/W
R _{thCH}	thermal resistance case to heatsin	k			0.5		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			35	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}; V_{R} = 0 \text{ V}$	$T_{vJ} = 45^{\circ}C$			340	Α
C	junction capacitance	$V_R = 12V$ f = 1 MHz	$T_{v_J} = 25^{\circ}C$		146		pF

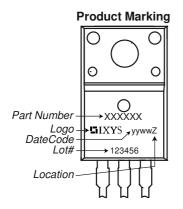
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Package TO-220FP					Ratings			
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					35	Α
T _{vJ}	virtual junction temperature				-55		175	°C
T _{op}	operation temperature				-55		150	°C
T _{stg}	storage temperature				-55		150	°C
Weight						2		g
M _D	mounting torque				0.4		0.6	Nm
F _c	mounting force with clip				20		60	Ν
d _{Spp/App}	creepage distance on surface si	triking distance through air	terminal to terminal	1.6	1.0			mm
d _{Spb/Apb}	creepage distance on surface si	inking distance through an	terminal to backside	2.5	2.5			mm
	isolation voltage	t = 1 second			2500			V
		t = 1 minute	50/60 Hz, RMS; liso⊾ ≤ 1 mA		2100			V



Part description

- D = Diode S = Schottky Diode

- A = low VF 30 = Current Rating [A] C = Common Cathode 100 = Reverse Voltage [V] PN = TO-220ABFP (3)

0	rdering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
S	standard	DSA30C100PN	DSA30C100PN	Tube	50	503508

Similar Part	Package	Voltage class
DSA30C100PB	TO-220AB (3)	100
DSA30C100HB	TO-247AD (3)	100
DSA30C100QB	TO-3P (3)	100

Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 175^{\circ}C$
	- Ro-	Schottky		
V _{0 max}	threshold voltage	0.46		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	9.2		mΩ

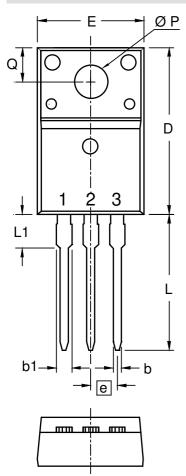
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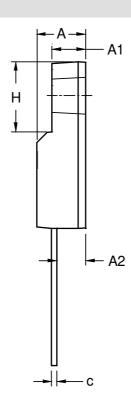
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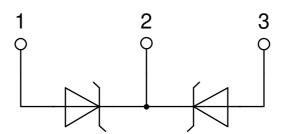
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Outlines TO-220FP





	Millim	neters	Inc	hes
Dim.	min	max	min	max
Α	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.56	2.96	0.101	0.117
b	0.70	0.90	0.028	0.035
С	0.45	0.60	0.018	0.024
D	15.67	16.07	0.617	0.633
Е	9.96	10.36	0.392	0.408
е	2.54	BSC	0.100	BSC
Н	6.48	6.88	0.255	0.271
L	12.68	13.28	0.499	0.523
L1	3.03	3.43	0.119	0.135
ØΡ	3.08	3.28	0.121	0.129
Q	3.20	3.40	0.126	0.134



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